

## **Bipolar Transistor**

60 V, 3 A, Low V<sub>CE(sat)</sub>, NPN Single TP/TP-FA

## 2SC6097

#### **Features**

- Adoption of FBET, MBIT Process
- Low Collector-to-Emitter Saturation Voltage
- High Allowable Power Dissipation
- Large Current Capacity
- High-Speed Switching

### **Applications**

 DC / DC Converter, Relay Drivers, Lamp Drivers, Motor Drivers, Inverter

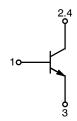
# SPECIFICATIONS ABSOLUTE MAXIMUM RATINGS at Ta = 25°C

| Parameter                    | Symbol           | Conditions            | Ratings         | Unit |
|------------------------------|------------------|-----------------------|-----------------|------|
| Collector to Base Voltage    | V <sub>CBO</sub> | -                     | 100             | V    |
| Collector to Emitter Voltage | V <sub>CES</sub> | -                     | 100             | V    |
| Collector to Emitter Voltage | V <sub>CEO</sub> | -                     | 60              | V    |
| Emitter to Base Voltage      | V <sub>EBO</sub> | -                     | 6.5             | V    |
| Collector Current            | I <sub>C</sub>   | -                     | 3               | Α    |
| Collector Current (Pulse)    | I <sub>CP</sub>  | -                     | 5               | Α    |
| Collector Current            | Ι <sub>Β</sub>   | -                     | 600             | mA   |
| Collector Dissipation        | P <sub>C</sub>   | -                     | 0.8             | W    |
|                              |                  | T <sub>C</sub> = 25°C | 15              | W    |
| Junction Temperature         | Tj               | -                     | 150             | °C   |
| Storage Temperature          | T <sub>stg</sub> | -                     | – 55 to<br>+150 | °C   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

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### **ELECTRICAL CONNECTION**



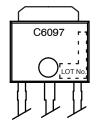


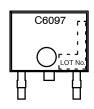


IPAK / TP CASE 369AJ

DPAK / TP-FA CASE 369AH

#### **MARKING DIAGRAM**





#### **ORDERING INFORMATION**

| Device       | Package          | Shipping <sup>†</sup> |
|--------------|------------------|-----------------------|
| 2SC6097-E    | SC-64,<br>TO-251 | 500 / Bulk Bag        |
| 2SC6097-TL-E | SC-63,<br>TO-252 | 700 / Tape &<br>Reel  |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

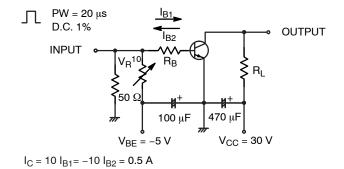
#### 2SC6097

## **ELECTRICAL CHARACTERISTICS** (at Ta = 25°C)

|   |                        |   | Ratings |      |     |      |
|---|------------------------|---|---------|------|-----|------|
| Parameter                               | Symbol                 | Conditions                                      | Min     | Тур  | Max | Unit |
| Collector Cutoff Current                | I <sub>CBO</sub>       | V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0 A    | -       | -    | 1   | μΑ   |
| Emitter Cutoff Current                  | I <sub>EBO</sub>       | V <sub>EB</sub> = 4 V, I <sub>C</sub> = 0 A     | -       | -    | 1   | μΑ   |
| DC Current Gain                         | h <sub>FE</sub>        | V <sub>CE</sub> = 2 V, I <sub>C</sub> = 100 mA  | 300     | -    | 600 |      |
| Gain-Bandwidth Product                  | f <sub>T</sub>         | V <sub>CE</sub> = 10 V, I <sub>C</sub> = 500 mA | -       | 390  | -   | MHz  |
| Output Capacitance                      | Cob                    | V <sub>CB</sub> = 10 V, f = 1MHz                | -       | 18   | -   | pF   |
| Collector to Emitter Saturation Voltage | V <sub>CE</sub> (sat)1 | I <sub>C</sub> = 1 A, I <sub>B</sub> = 50 mA    | -       | 100  | 150 | mV   |
|   | V <sub>CE</sub> (sat)2 | I <sub>C</sub> = 1 A, I <sub>B</sub> = 100 mA   | -       | 90   | 135 | mV   |
| Base to Emitter Saturation Voltage      | V <sub>BE</sub> (sat)  | I <sub>C</sub> = 1 A, I <sub>B</sub> = 100 mA   | -       | 0.84 | 1.2 | V    |
| Collector to Base Breakdown Voltage     | V <sub>(BR)CBO</sub>   | $I_C = 10 \mu A, I_E = 0 A$                     | 100     | -    | -   | V    |
| Collector to Emitter Breakdown Voltage  | V <sub>(BR)CES</sub>   | $I_C$ = 100 $\mu$ A, $R_{BE}$ = 0 $\Omega$      | 100     | -    | -   | V    |
| Collector to Emitter Breakdown Voltage  | V <sub>(BR)CEO</sub>   | $I_C = 1 \text{ mA}, R_{BE} = \infty$           | 60      | -    | -   | V    |
| Emittert o Base Breakdown Voltage       | V <sub>(BR)EBO</sub>   | $I_E = 10 \mu A, I_C = 0 A$                     | 6.5     | -    | -   | V    |
| Turn-On Time                            | t <sub>on</sub>        | See specified Test Circuit                      | -       | 35   | -   | ns   |
| Storage Time                            | t <sub>stg</sub>       | 1   | -       | 680  | -   | ns   |
| Fall Time                               | t <sub>f</sub>         | 1   | -       | 24   | -   | ns   |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## **Switching Time Test Circuit**



### 2SC6097

#### **TYPICAL CHARACTERISTICS**

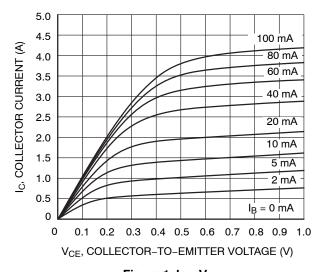
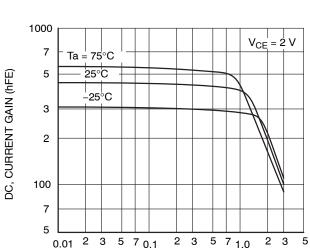


Figure 1.  $I_C - V_{CE}$ 



I<sub>C</sub>, COLLECTOR CURRENT (A) Figure 3. H<sub>FE</sub> – I<sub>C</sub>

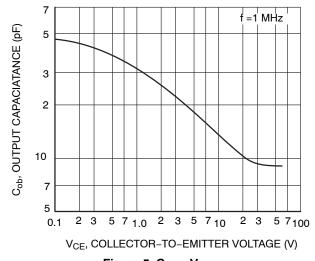


Figure 5. C<sub>ob</sub> - V<sub>CB</sub>

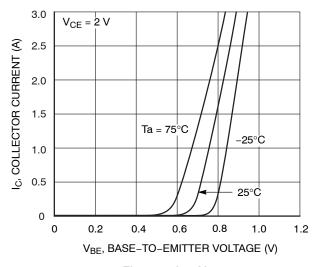


Figure 2.  $I_C - V_{BE}$ 

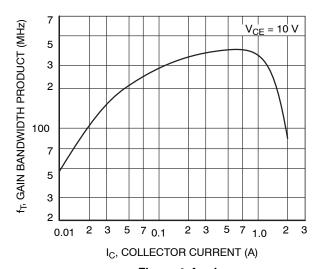


Figure 4. f<sub>T</sub> - I<sub>C</sub>

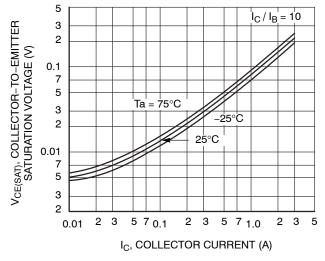
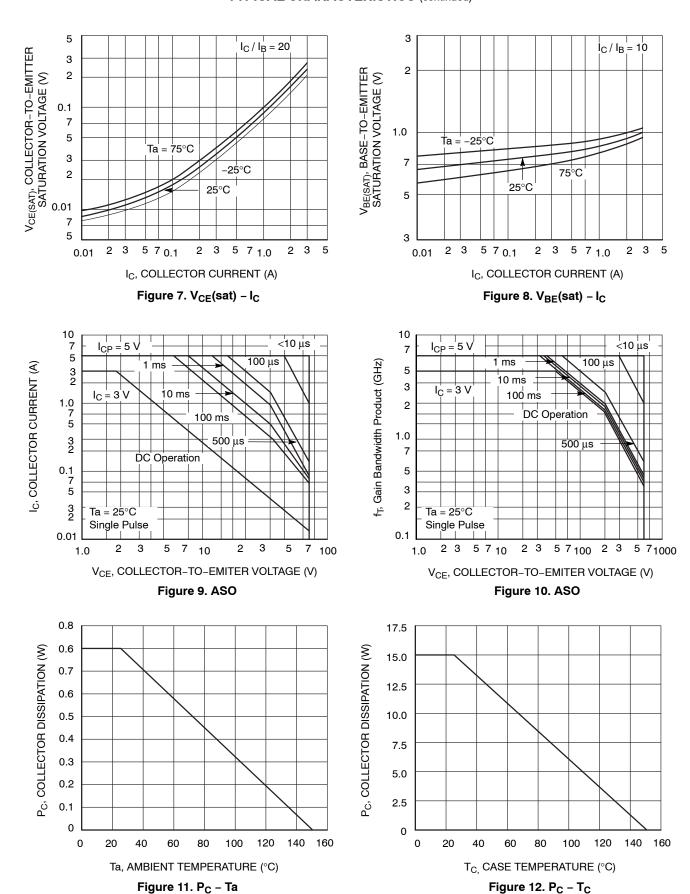


Figure 6. V<sub>CE</sub>(sat) - I<sub>C</sub>

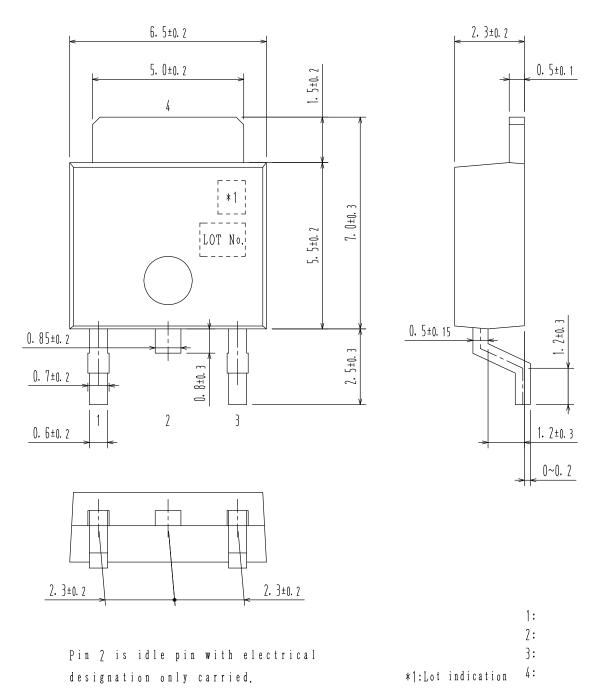
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### TYPICAL CHARACTERISTICS (continued)



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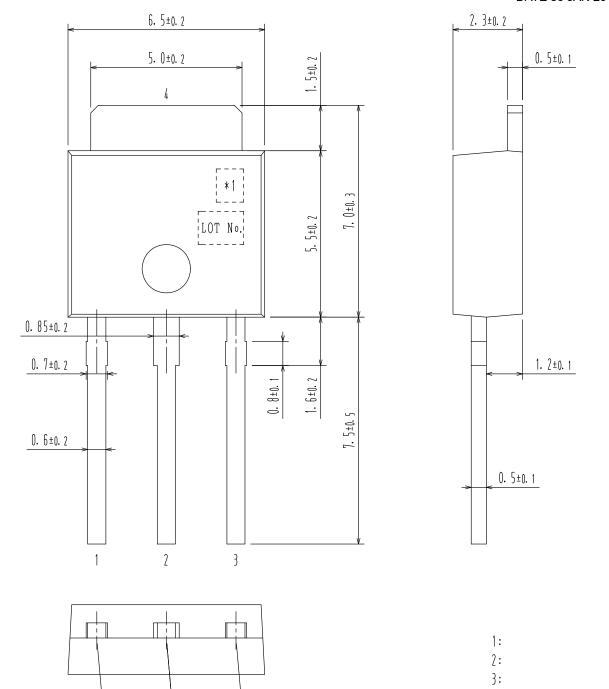


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\*1:Lot indication

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